

# 74LVC1G332-Q100

## Single 3-input OR gate

Rev. 6 — 18 August 2023

Product data sheet

## 1. General description

The 74LVC1G332-Q100 is a single 3-input OR gate. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and -40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Overvoltage tolerant inputs to 5.5 V
- $\pm 24$  mA output drive ( $V_{CC} = 3.0$  V)
- CMOS low power dissipation
- Direct interface with TTL levels
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 250 mA
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

## 3. Ordering information

Table 1. Ordering information

| Type number                       | Package           |              |                                                                        |                          |
|-----------------------------------|-------------------|--------------|------------------------------------------------------------------------|--------------------------|
|                                   | Temperature range | Name         | Description                                                            | Version                  |
| <a href="#">74LVC1G332GW-Q100</a> | -40 °C to +125 °C | TSSOP6       | plastic thin shrink small outline package; 6 leads; body width 1.25 mm | <a href="#">SOT363-2</a> |
| <a href="#">74LVC1G332GV-Q100</a> | -40 °C to +125 °C | SC-74; TSOP6 | plastic surface-mounted package; 6 leads                               | <a href="#">SOT457</a>   |

4. Marking

Table 2. Marking

| Type number       | Marking code <sup>[1]</sup> |
|-------------------|-----------------------------|
| 74LVC1G332GW-Q100 | YG                          |
| 74LVC1G332GV-Q100 | YG                          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

**Fig. 1. Logic symbol**

**Fig. 2. IEC logic symbol**

**Fig. 3. Logic diagram**

6. Pinning information

6.1. Pinning

**GW package**  
**SOT363-2 (TSSOP6)**

**GV package**  
**SOT457 (SC-74; TSOP6)**

6.2. Pin description

Table 3. Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| A               | 1   | data input     |
| GND             | 2   | ground (0 V)   |
| B               | 3   | data input     |
| Y               | 4   | data output    |
| V <sub>CC</sub> | 5   | supply voltage |
| C               | 6   | data input     |

## 7. Functional description

**Table 4. Function table**

H = HIGH voltage level; L = LOW voltage level; X = don't care.

| Input |   |   | Output |
|-------|---|---|--------|
| A     | B | C | Y      |
| H     | X | X | H      |
| X     | H | X | H      |
| X     | X | H | H      |
| L     | L | L | L      |

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                          | Min  | Max            | Unit |
|-----------|-------------------------|-------------------------------------|------|----------------|------|
| $V_{CC}$  | supply voltage          |                                     | -0.5 | +6.5           | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                         | -50  | -              | mA   |
| $V_I$     | input voltage           | [1]                                 | -0.5 | +6.5           | V    |
| $I_{OK}$  | output clamping current | $V_O > V_{CC}$ or $V_O < 0$ V       | -    | ±50            | mA   |
| $V_O$     | output voltage          | Active mode [1]                     | -0.5 | $V_{CC} + 0.5$ | V    |
|           |                         | Power-down mode; $V_{CC} = 0$ V [1] | -0.5 | +6.5           | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$             | -    | ±50            | mA   |
| $I_{CC}$  | supply current          |                                     | -    | 100            | mA   |
| $I_{GND}$ | ground current          |                                     | -100 | -              | mA   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to $+125$ °C [2] | -    | 250            | mW   |
| $T_{stg}$ | storage temperature     |                                     | -65  | +150           | °C   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT363-2 (TSSOP6) package:  $P_{tot}$  derates linearly with 3.7 mW/K above 83 °C.

For SOT457 (SC-74; TSOP6) package:  $P_{tot}$  derates linearly with 4.1 mW/K above 89 °C.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

| Symbol              | Parameter                           | Conditions                      | Min  | Typ | Max      | Unit |
|---------------------|-------------------------------------|---------------------------------|------|-----|----------|------|
| $V_{CC}$            | supply voltage                      |                                 | 1.65 | -   | 5.5      | V    |
| $V_I$               | input voltage                       |                                 | 0    | -   | 5.5      | V    |
| $V_O$               | output voltage                      | Active mode                     | 0    | -   | $V_{CC}$ | V    |
|                     |                                     | Power-down mode; $V_{CC} = 0$ V | 0    | -   | 5.5      | V    |
| $T_{amb}$           | ambient temperature                 |                                 | -40  | -   | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 1.65$ V to $2.7$ V    | -    | -   | 20       | ns/V |
|                     |                                     | $V_{CC} = 2.7$ V to $5.5$ V     | -    | -   | 10       | ns/V |

## 10. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                 | Conditions                                                                                                | -40 °C to +85 °C       |        |                        | -40 °C to +125 °C      |                        | Unit |
|------------------|---------------------------|-----------------------------------------------------------------------------------------------------------|------------------------|--------|------------------------|------------------------|------------------------|------|
|                  |                           |                                                                                                           | Min                    | Typ[1] | Max                    | Min                    | Max                    |      |
| V <sub>IH</sub>  | HIGH-level input voltage  | V <sub>CC</sub> = 1.65 V to 1.95 V                                                                        | 0.65 × V <sub>CC</sub> | -      | -                      | 0.65 × V <sub>CC</sub> | -                      | V    |
|                  |                           | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                          | 1.7                    | -      | -                      | 1.7                    | -                      | V    |
|                  |                           | V <sub>CC</sub> = 2.7 V to 3.6 V                                                                          | 2.0                    | -      | -                      | 2.0                    | -                      | V    |
|                  |                           | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                          | 0.7 × V <sub>CC</sub>  | -      | -                      | 0.7 × V <sub>CC</sub>  | -                      | V    |
| V <sub>IL</sub>  | LOW-level input voltage   | V <sub>CC</sub> = 1.65 V to 1.95 V                                                                        | -                      | -      | 0.35 × V <sub>CC</sub> | -                      | 0.35 × V <sub>CC</sub> | V    |
|                  |                           | V <sub>CC</sub> = 2.3 V to 2.7 V                                                                          | -                      | -      | 0.7                    | -                      | 0.7                    | V    |
|                  |                           | V <sub>CC</sub> = 2.7 V to 3.6 V                                                                          | -                      | -      | 0.8                    | -                      | 0.8                    | V    |
|                  |                           | V <sub>CC</sub> = 4.5 V to 5.5 V                                                                          | -                      | -      | 0.3 × V <sub>CC</sub>  | -                      | 0.3 × V <sub>CC</sub>  | V    |
| V <sub>OH</sub>  | HIGH-level output voltage | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                       |                        |        |                        |                        |                        |      |
|                  |                           | I <sub>O</sub> = -100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                               | V <sub>CC</sub> - 0.1  | -      | -                      | V <sub>CC</sub> - 0.1  | -                      | V    |
|                  |                           | I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V                                                          | 1.2                    | -      | -                      | 0.95                   | -                      | V    |
|                  |                           | I <sub>O</sub> = -8 mA; V <sub>CC</sub> = 2.3 V                                                           | 1.9                    | -      | -                      | 1.7                    | -                      | V    |
|                  |                           | I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V                                                          | 2.2                    | -      | -                      | 1.9                    | -                      | V    |
|                  |                           | I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V                                                          | 2.3                    | -      | -                      | 2.0                    | -                      | V    |
|                  |                           | I <sub>O</sub> = -32 mA; V <sub>CC</sub> = 4.5 V                                                          | 3.8                    | -      | -                      | 3.4                    | -                      | V    |
| V <sub>OL</sub>  | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                       |                        |        |                        |                        |                        |      |
|                  |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                                | -                      | -      | 0.1                    | -                      | 0.1                    | V    |
|                  |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V                                                           | -                      | -      | 0.45                   | -                      | 0.70                   | V    |
|                  |                           | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V                                                            | -                      | -      | 0.3                    | -                      | 0.45                   | V    |
|                  |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                                                           | -                      | -      | 0.4                    | -                      | 0.60                   | V    |
|                  |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V                                                           | -                      | -      | 0.55                   | -                      | 0.80                   | V    |
|                  |                           | I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V                                                           | -                      | -      | 0.55                   | -                      | 0.80                   | V    |
| I <sub>I</sub>   | input leakage current     | V <sub>CC</sub> = 0 V to 5.5 V; V <sub>I</sub> = 5.5 V or GND                                             | -                      | ±0.1   | ±1                     | -                      | ±1                     | µA   |
| I <sub>OFF</sub> | power-off leakage current | V <sub>CC</sub> = 0 V; V <sub>I</sub> or V <sub>O</sub> = 5.5 V                                           | -                      | ±0.1   | ±2                     | -                      | ±2                     | µA   |
| I <sub>CC</sub>  | supply current            | V <sub>CC</sub> = 1.65 V to 5.5 V; V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A          | -                      | 0.1    | 4                      | -                      | 4                      | µA   |
| ΔI <sub>CC</sub> | additional supply current | per pin; V <sub>CC</sub> = 2.3 V to 5.5 V; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A | -                      | 5      | 500                    | -                      | 500                    | µA   |
| C <sub>I</sub>   | input capacitance         | V <sub>CC</sub> = 3.3 V; V <sub>I</sub> = GND to V <sub>CC</sub>                                          | -                      | 3      | -                      | -                      | -                      | pF   |

[1] All typical values are measured at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C.

11. Dynamic characteristics

**Table 8. Dynamic characteristics**  
 Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5.

| Symbol          | Parameter                     | Conditions                                                            | -40 °C to +85 °C |        |      | -40 °C to +125 °C |      | Unit |
|-----------------|-------------------------------|-----------------------------------------------------------------------|------------------|--------|------|-------------------|------|------|
|                 |                               |                                                                       | Min              | Typ[1] | Max  | Min               | Max  |      |
| t <sub>pd</sub> | propagation delay             | A, B and C to Y; see Fig. 4 [2]                                       |                  |        |      |                   |      |      |
|                 |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                                    | 1.5              | 4.7    | 17.2 | 1.5               | 21.5 | ns   |
|                 |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                                      | 1.0              | 3.0    | 6.2  | 1.0               | 7.8  | ns   |
|                 |                               | V <sub>CC</sub> = 2.7 V                                               | 1.0              | 3.0    | 6.0  | 1.0               | 7.5  | ns   |
|                 |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                      | 1.0              | 2.6    | 4.8  | 1.0               | 6.2  | ns   |
|                 |                               | V <sub>CC</sub> = 4.5 V to 5.5 V                                      | 1.0              | 1.9    | 3.5  | 1.0               | 4.4  | ns   |
| C <sub>PD</sub> | power dissipation capacitance | V <sub>I</sub> = GND to V <sub>CC</sub> ; V <sub>CC</sub> = 3.3 V [3] | -                | 12     | -    | -                 | -    | pF   |

- [1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.
- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
- [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:  
 f<sub>i</sub> = input frequency in MHz;  
 f<sub>o</sub> = output frequency in MHz;  
 C<sub>L</sub> = output load capacitance in pF;  
 V<sub>CC</sub> = supply voltage in V;  
 N = number of inputs switching;  
 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

11.1. Waveforms and test circuit

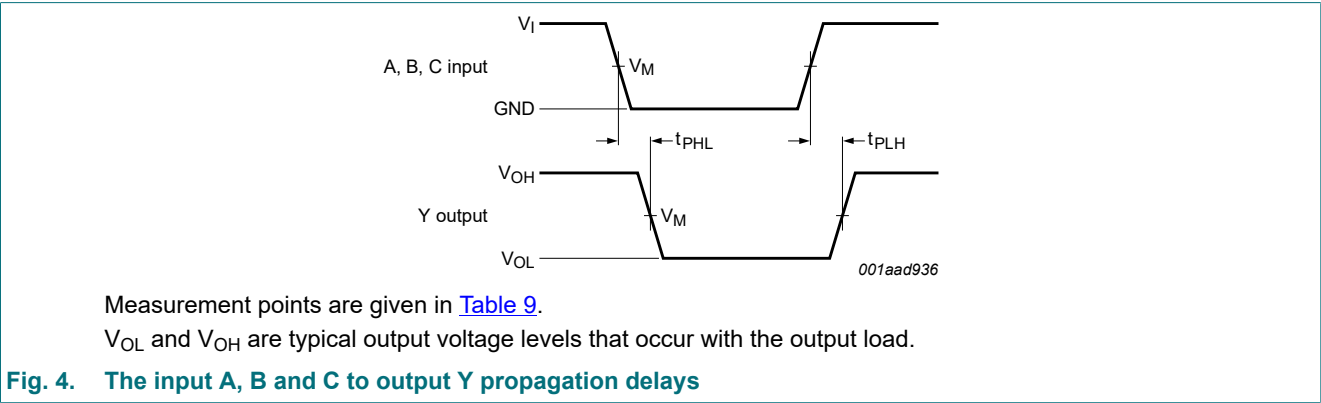
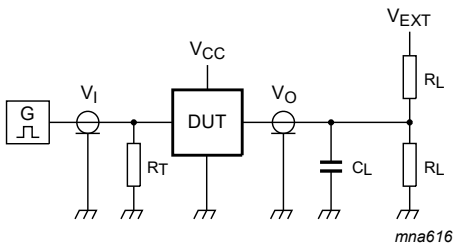


Table 9. Measurement points

| Supply voltage   | Input                 | Output                |
|------------------|-----------------------|-----------------------|
| V <sub>CC</sub>  | V <sub>M</sub>        | V <sub>M</sub>        |
| 1.65 V to 1.95 V | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 2.3 V to 2.7 V   | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 2.7 V            | 1.5 V                 | 1.5 V                 |
| 3.0 V to 3.6 V   | 1.5 V                 | 1.5 V                 |
| 4.5 V to 5.5 V   | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |



Test data is given in [Table 10](#).  
Definitions for test circuit:  
 $R_L$  = Load resistance;  
 $C_L$  = Load capacitance including jig and probe capacitance;  
 $R_T$  = Termination resistance; should be equal to the output impedance  $Z_o$  of the pulse generator;  
 $V_{EXT}$  = External voltage for measuring switching times.

Fig. 5. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage   | Input    |                       | Load  |              | $V_{EXT}$          |
|------------------|----------|-----------------------|-------|--------------|--------------------|
| $V_{CC}$         | $V_I$    | $t_r = t_f$           | $C_L$ | $R_L$        | $t_{PLH}, t_{PHL}$ |
| 1.65 V to 1.95 V | $V_{CC}$ | $\leq 2.0 \text{ ns}$ | 30 pF | 1 k $\Omega$ | open               |
| 2.3 V to 2.7 V   | $V_{CC}$ | $\leq 2.0 \text{ ns}$ | 30 pF | 500 $\Omega$ | open               |
| 2.7 V            | 2.7 V    | $\leq 2.5 \text{ ns}$ | 50 pF | 500 $\Omega$ | open               |
| 3.0 V to 3.6 V   | 2.7 V    | $\leq 2.5 \text{ ns}$ | 50 pF | 500 $\Omega$ | open               |
| 4.5 V to 5.5 V   | $V_{CC}$ | $\leq 2.5 \text{ ns}$ | 50 pF | 500 $\Omega$ | open               |

12. Package outline

TSSOP6: plastic thin shrink small outline package; 6 leads; body width 1.25 mm

SOT363-2

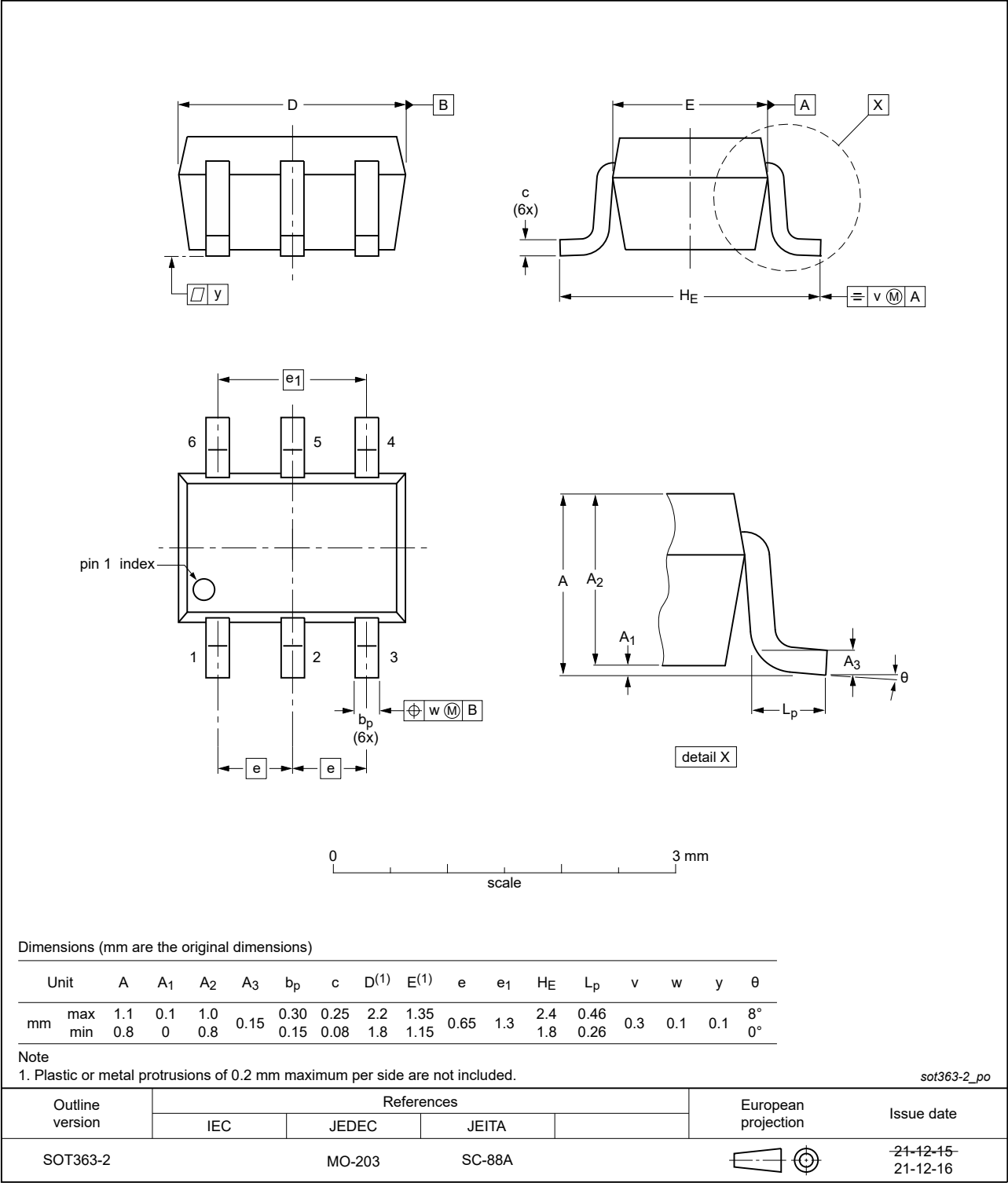


Fig. 6. Package outline SOT363-2 (TSSOP6)

Plastic, surface-mounted package (SC-74; TSOP6); 6 leads

SOT457

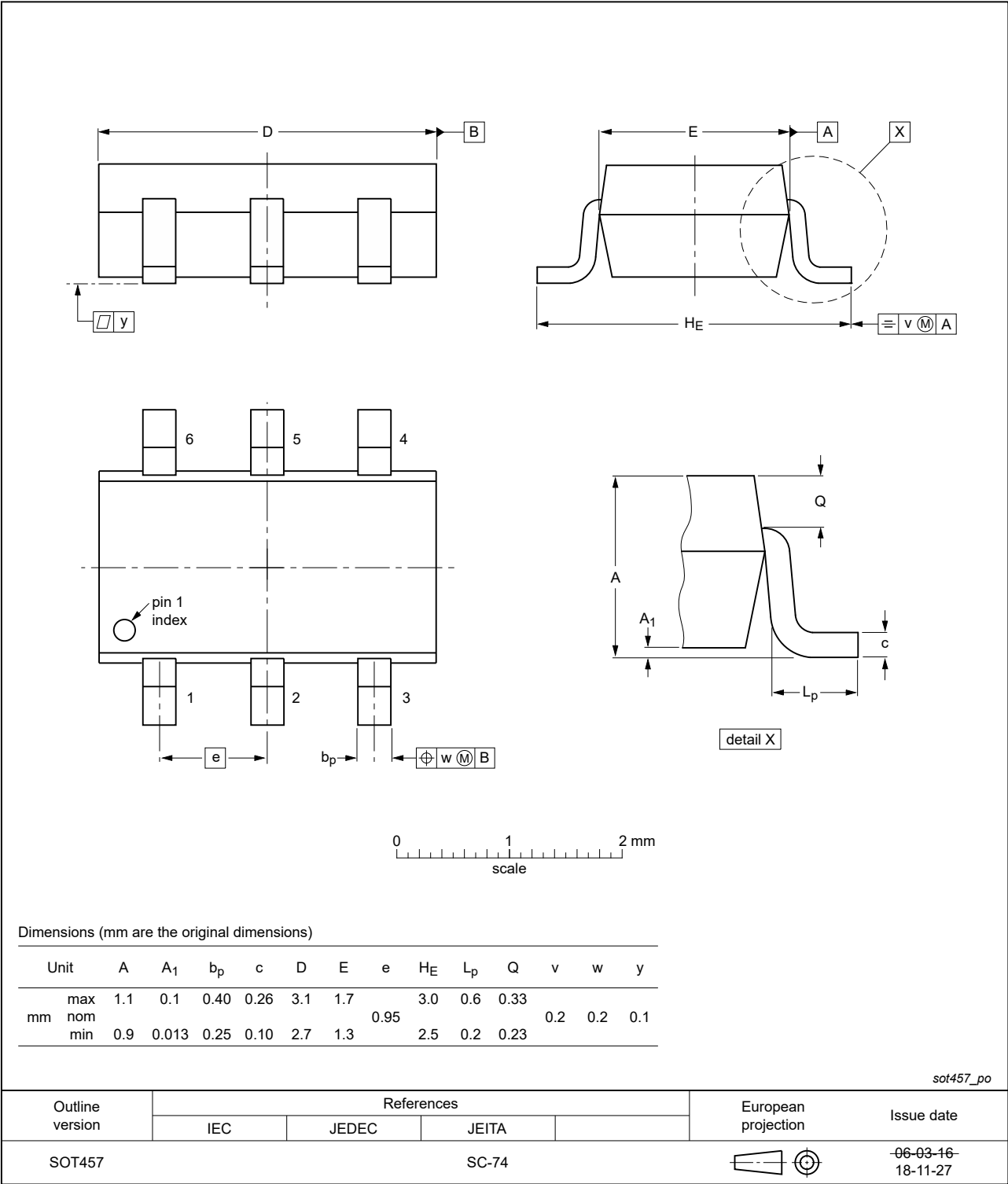


Fig. 7. Package outline SOT457 (SC-74; TSOP6)



13. Abbreviations

Table 11. Abbreviations

| Acronym | Description                             |
|---------|-----------------------------------------|
| CDM     | Charged Device Model                    |
| CMOS    | Complementary Metal Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| TTL     | Transistor-Transistor Logic             |

14. Revision history

Table 12. Revision history

| Document ID         | Release date                                                                                                                                                                                                                             | Data sheet status  | Change notice | Supersedes          |
|---------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|---------------|---------------------|
| 74LVC1G332_Q100 v.6 | 20230818                                                                                                                                                                                                                                 | Product data sheet | -             | 74LVC1G332_Q100 v.5 |
| Modifications:      | <ul style="list-style-type: none"><li><a href="#">Section 2</a>: ESD specification updated according to the latest JEDEC standard.</li></ul>                                                                                             |                    |               |                     |
| 74LVC1G332_Q100 v.5 | 20220207                                                                                                                                                                                                                                 | Product data sheet | -             | 74LVC1G332_Q100 v.4 |
| Modifications:      | <ul style="list-style-type: none"><li>Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6).</li></ul>                                                                                                                                     |                    |               |                     |
| 74LVC1G332_Q100 v.4 | 20210921                                                                                                                                                                                                                                 | Product data sheet | -             | 74LVC1G332_Q100 v.3 |
| Modifications:      | <ul style="list-style-type: none"><li><a href="#">Table 5</a>: Derating values for P<sub>tot</sub> total power dissipation updated.</li><li><a href="#">Fig. 7</a>: Package outline drawing SOT457 (SC-74; TSOP6) has changed.</li></ul> |                    |               |                     |
| 74LVC1G332_Q100 v.3 | 20180821                                                                                                                                                                                                                                 | Product data sheet | -             | 74LVC1G332_Q100 v.2 |
| Modifications:      | <ul style="list-style-type: none"><li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li><li>Legal texts have been adapted to the new company name where appropriate.</li></ul>   |                    |               |                     |
| 74LVC1G332_Q100 v.2 | 20161209                                                                                                                                                                                                                                 | Product data sheet | -             | 74LVC1G332_Q100 v.1 |
| Modifications:      | <ul style="list-style-type: none"><li><a href="#">Table 7</a>: The maximum limits for leakage current and supply current have changed.</li></ul>                                                                                         |                    |               |                     |
| 74LVC1G332_Q100 v.1 | 20140526                                                                                                                                                                                                                                 | Product data sheet | -             | -                   |

## 15. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition                                                                            |
|--------------------------------|--------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

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## Contents

|                                                 |           |
|-------------------------------------------------|-----------|
| <b>1. General description.....</b>              | <b>1</b>  |
| <b>2. Features and benefits.....</b>            | <b>1</b>  |
| <b>3. Ordering information.....</b>             | <b>1</b>  |
| <b>4. Marking.....</b>                          | <b>2</b>  |
| <b>5. Functional diagram.....</b>               | <b>2</b>  |
| <b>6. Pinning information.....</b>              | <b>2</b>  |
| 6.1. Pinning.....                               | 2         |
| 6.2. Pin description.....                       | 2         |
| <b>7. Functional description.....</b>           | <b>3</b>  |
| <b>8. Limiting values.....</b>                  | <b>3</b>  |
| <b>9. Recommended operating conditions.....</b> | <b>3</b>  |
| <b>10. Static characteristics.....</b>          | <b>4</b>  |
| <b>11. Dynamic characteristics.....</b>         | <b>5</b>  |
| 11.1. Waveforms and test circuit.....           | 5         |
| <b>12. Package outline.....</b>                 | <b>7</b>  |
| <b>13. Abbreviations.....</b>                   | <b>9</b>  |
| <b>14. Revision history.....</b>                | <b>9</b>  |
| <b>15. Legal information.....</b>               | <b>10</b> |

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